

1. General description

Planar passivated high commutation three quadrant triac in a SOT186A (TO-220F) "full pack" plastic package. This "series E" triac balances the requirements of commutation performance and gate sensitivity and is intended for interfacing with low power drivers including microcontrollers.

2. Features and benefits

- 3Q technology for improved noise immunity
- Direct interfacing with low power drivers and microcontrollers
- Good immunity to false turn-on by dV/dt
- High commutation capability with sensitive gate
- High voltage capability
- Isolated mounting base package
- Planar technology for voltage ruggedness and reliability
- Sensitive gate for easy logic level triggering
- Triggering in three quadrants only

3. Applications

- General purpose motor controls
- Large and small appliances (White Goods)
- Loads such as contactors, circuit breakers, valves, dispensers and door locks
- Lower-power highly inductive, resistive and safety loads

4. Quick reference data

| Table 1. Qui | ck reference data | | | | | | |
|------------------------|--|---|--|-----|-----|-----|------|
| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
| V _{DRM} | repetitive peak off- state voltage | | | - | - | 600 | V |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4; Fig. 5</u> | | - | - | 14 | A |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _h ≤ 110 °C; <u>Fig. 1;</u> Fig. 2; <u>Fig. 3</u> | | - | - | 2 | A |
| Static characteristics | | | | | | | |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | | 0.5 | - | 10 | mA |





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| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------|-----------|--|-----|-----|-----|------|
| | | $V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \text{ T2+ G-};$ $T_j = 25 \text{ °C}; \frac{\text{Fig. 7}}{7}$ | 0.5 | - | 10 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | 0.5 | - | 10 | mA |

5. Pinning information

| Table 2. | Pinning | information | | |
|----------|---------|-------------------------|--------------------|----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | T1 | main terminal 1 | mb | T2 |
| 2 | T2 | main terminal 2 | | sym051 |
| 3 | G | gate | | |
| mb | n.c. | mounting base; isolated | | |
| | | | TO-220F (SOT186A) | |

6. Ordering information

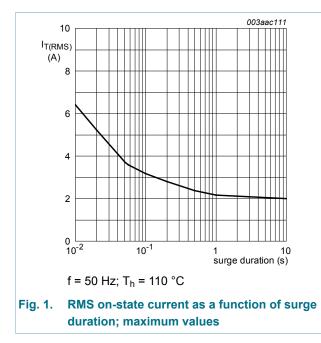
| Table 3. Ordering information | | | | | | | |
|-------------------------------|---------|---|---------|--|--|--|--|
| Type number | Package | | | | | | |
| | Name | Description | Version | | | | |
| BTA202X-600E | TO-220F | plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack" | SOT186A | | | | |

7. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|--------------------------------------|---|-----|------|------------------|
| V _{DRM} | repetitive peak off-state voltage | | - | 600 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_h \le 110 \text{ °C}$; Fig. 1; Fig. 2; Fig. 3 | - | 2 | A |
| I _{TSM} | non-repetitive peak on-state current | full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; \text{ Fig. 4; Fig. 5}$ | - | 14 | A |
| | | full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 16.7 \text{ ms}$ | - | 15.4 | A |
| l ² t | I2t for fusing | t _p = 10 ms; SIN | - | 0.98 | A ² s |
| dI _T /dt | rate of rise of on-state current | I_T = 1.5 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs | - | 100 | A/µs |
| I _{GM} | peak gate current | | - | 2 | А |
| P _{GM} | peak gate power | | - | 5 | W |
| P _{G(AV)} | average gate power | over any 20 ms period | - | 0.5 | W |
| T _{stg} | storage temperature | | -40 | 150 | °C |
| Tj | junction temperature | | - | 125 | °C |



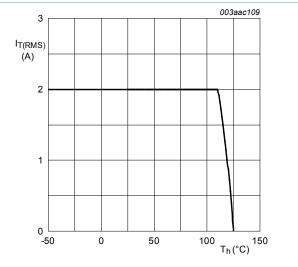
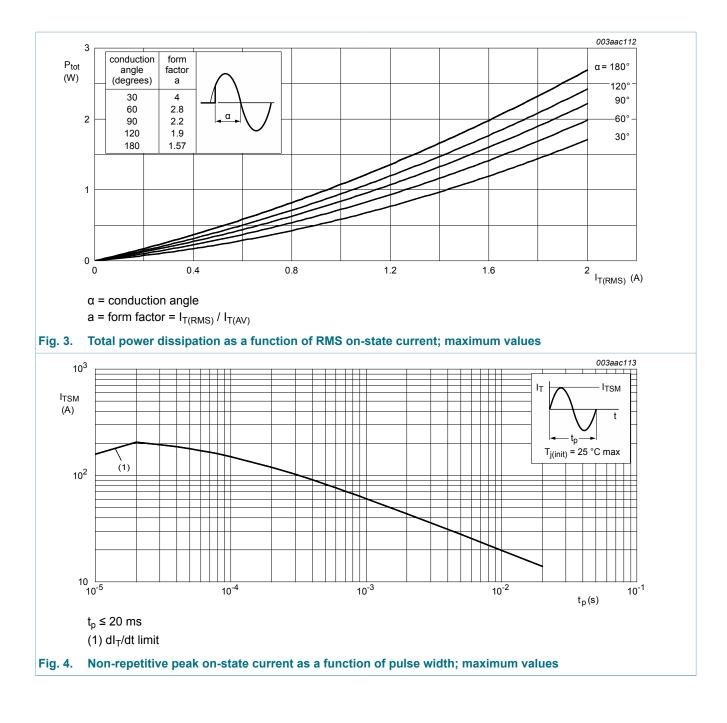


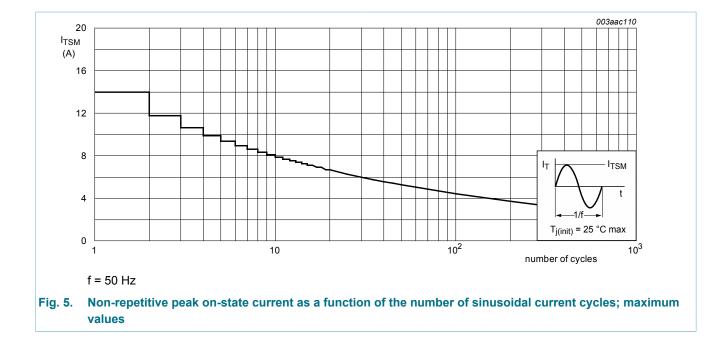
Fig. 2. RMS on-state current as a function of heatsink temperature; maximum values

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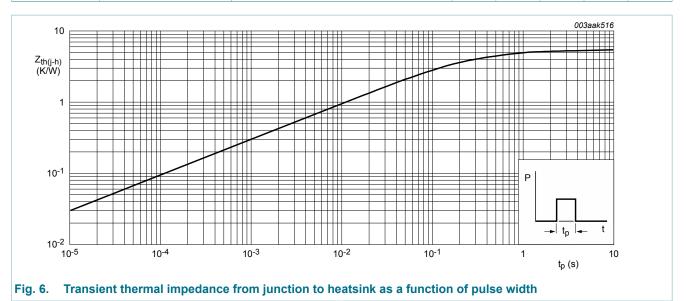
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8. Thermal characteristics

| Table 5. | Thermal characteristics | | | | | |
|----------------------|--|---|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| R _{th(j-h)} | thermal resistance from junction to heatsink | full cycle; with heatsink compound; Fig. 6 | - | - | 5.5 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | - | 55 | - | K/W |



9. Isolation characteristics

| Table 6. Isolation characteristics | | | | | | | | |
|------------------------------------|-----------------------|---|--|-----|-----|------|------|--|
| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit | |
| V _{isol(RMS)} | RMS isolation voltage | from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz \leq f \leq 60 Hz; RH \leq 65 %; T _h = 25 °C | | - | - | 2500 | V | |
| C _{isol} | isolation capacitance | from main terminal 2 to external heatsink; f = 1 MHz | | - | 10 | - | pF | |

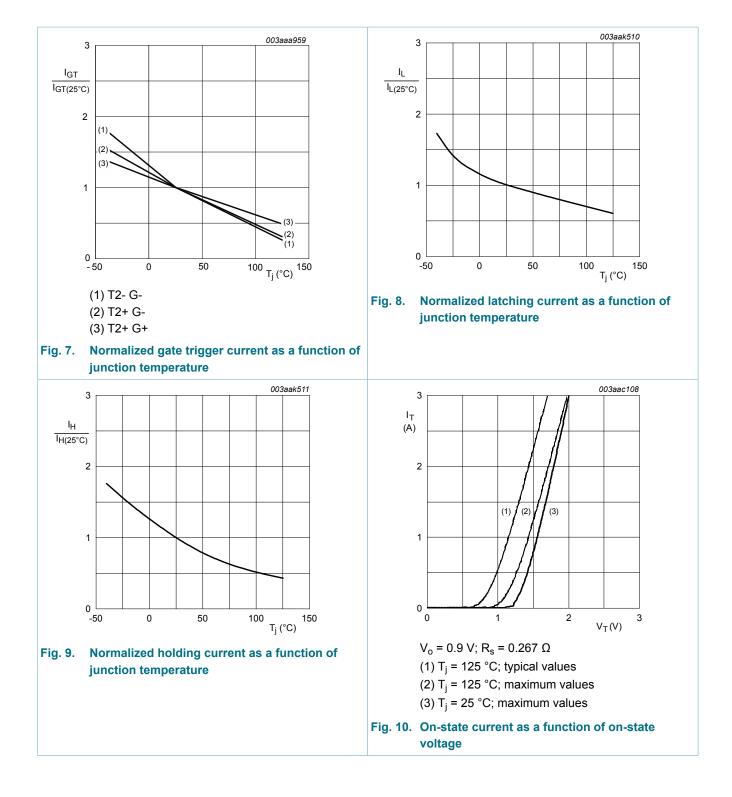
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10. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------|---|-----|------|-----|------|
| Static chara | acteristics | | | | | |
| I _{GT} | gate trigger current | $V_D = 12 V; I_T = 0.1 A; T2+G+;$ $T_j = 25 °C; Fig. 7$ | 0.5 | - | 10 | mA |
| | | $V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; Fig. 7 | 0.5 | - | 10 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | 0.5 | - | 10 | mA |
| IL | latching current | V _D = 12 V; I _G = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 8</u> | - | - | 12 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 8</u> | - | - | 20 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 8</u> | - | - | 12 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u> | - | - | 10 | mA |
| V _T | on-state voltage | I _T = 3 A; T _j = 25 °C; <u>Fig. 10</u> | - | 1.63 | 2 | V |
| V _{GT} | gate trigger voltage | V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11 | - | 0.7 | 1 | V |
| | | V _D = 400 V; I _T = 0.1 A; T _j = 125 °C; Fig. 11 | 0.2 | 0.3 | - | V |
| I _D | off-state current | V _D = 600 V; T _j = 125 °C | - | 0.1 | 0.5 | mA |
| Dynamic cł | naracteristics | | | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 402 V; T _j = 125 °C; R _{GT1} = 220 Ω; (V _{DM} = 67% of V _{DRM}); exponential waveform | - | 500 | - | V/µs |
| dI _{com} /dt | rate of change of commutating current | $\label{eq:VD} \begin{split} V_D &= 400 \; \text{V}; \; \text{T}_j = 125 \; ^{\circ}\text{C}; \; \text{I}_{\text{T}(\text{RMS})} = 2 \; \text{A}; \\ \text{d} V_{\text{com}}/\text{d}t &= 20 \; \text{V}/\mu\text{s}; \; (\text{snubberless} \\ \text{condition}); \; \text{gate open circuit} \end{split}$ | 2 | - | - | A/m |
| | | $\label{eq:VD} \begin{array}{l} V_D = 400 \text{ V}; T_j = 125 \ ^\circ\text{C}; I_{T(\text{RMS})} = 2 \text{ A}; \\ \text{d} V_{\text{com}}/\text{d} t = 10 \text{ V}/\mu\text{s}; \text{ gate open circuit} \end{array}$ | 2.3 | - | - | A/m |
| | | | | | | |

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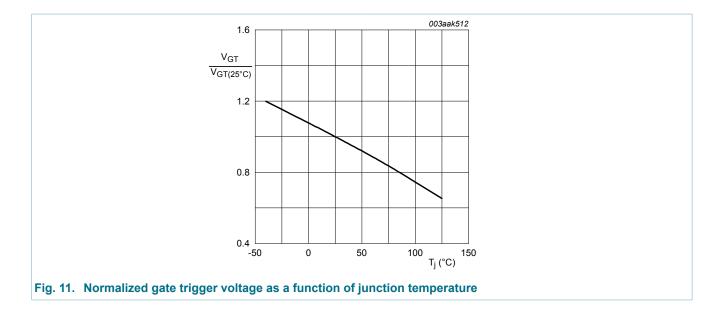


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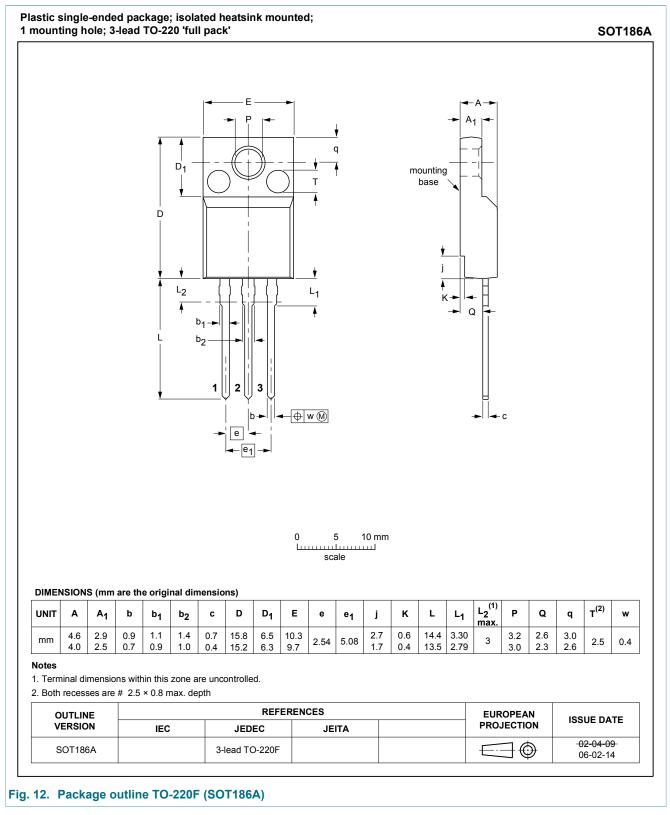
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11. Package outline



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